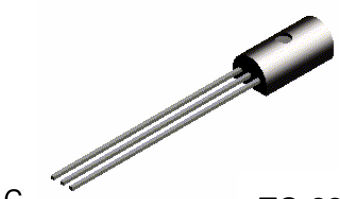
FAIRCHILD
SEMICONDUCTOR TM

TN6716A



C B E

TO-226

NPN General Purpose Amplifier

This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 1.2A. Sourced from Process 38. See TN6715A for characteristics.

Absolute Maximum Ratings*

$T_{A = 25°C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	60	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current - Continuous	2	A
$T_{J, Tstg}$	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150°C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

$T_{A = 25°C}$ unless otherwise noted

Symbol	Characteristic	Max	Units
		T_A=25°C	
P_D	Total Device Dissipation Derate above 25°C	1 8	W mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	125	°C/W

NPN General Purpose Amplifier
(continued)

Electrical Characteristics
$T_{A = 25°C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 1 mA	60		V
BV_{CBO}	Collector-Base Breakdown Voltage	I_C = 100 μA	60		V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E = 1 mA	5		V
I_{CBO}	Collector Cutoff Current	V_{CB} = 40 V		100	nA
I_{EBO}	Emitter Cutoff Current	V_{EB} = 5 V		10	uA
ON CHARACTERISTICS					
h_{FE}	DC Current Gain	I_C = 50 mA, V_{CE} = 1 V I_C = 250 mA, V_{CE} = 1 V I_C = 500 mA, V_{CE} = 1 V	80 50 20	250	-
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I_C = 250 mA, I_B = 10 mA I_C = 250 mA, I_B = 25 mA		0.5 0.35	V
$V_{BE(on)}$	Base-Emitter On Voltage	I_C = 250 mA, V_{CE} = 1.0 V		1.2	V
SMALL SIGNAL CHARACTERISTICS					
C_{cb}	Output Capacitance	V_{CB} = 10 V, I_E = 0, f = 1MHz		30	pF
hfe	Small Signal Current Gain	I_C = 200 mA,V_{CE} = 5 V,f=20MHz	2.5	25	MHz

*Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 1.0%

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™
CoolFET™
CROSSVOLT™
E^2CMOS^{TM}
FACT™
FACT Quiet Series™
FAST®
FASTr™
GTO™
HiSeC™
ISOPLANAR™
MICROWIRE™
POP™
PowerTrench®
QFET™
QS™
Quiet Series™
SuperSOT™-3
SuperSOT™-6
SuperSOT™-8
SyncFET™
TinyLogic™
UHC™
VCX™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.
As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.